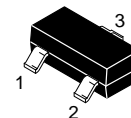
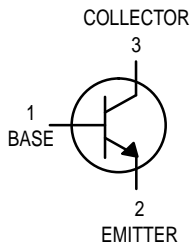


# General Purpose Transistor

## NPN Silicon

**BCW33LT1**



CASE 318-08, STYLE 6  
SOT-23 (TO-236AB)

### MAXIMUM RATINGS

| Rating                         | Symbol    | Value | Unit |
|--------------------------------|-----------|-------|------|
| Collector–Emitter Voltage      | $V_{CEO}$ | 20    | Vdc  |
| Collector–Base Voltage         | $V_{CBO}$ | 30    | Vdc  |
| Emitter–Base Voltage           | $V_{EBO}$ | 5.0   | Vdc  |
| Collector Current — Continuous | $I_C$     | 100   | mAdc |

### THERMAL CHARACTERISTICS

| Characteristic  | Symbol          | Max         | Unit                      |
|---|-----------------|-------------|---------------------------|
| Total Device Dissipation FR-5 Board <sup>(1)</sup><br>$T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$         | $P_D$           | 225         | mW                        |
|   |                 | 1.8         | mW/ $^\circ\text{C}$      |
| Thermal Resistance, Junction to Ambient   | $R_{\theta JA}$ | 556         | $^\circ\text{C}/\text{W}$ |
| Total Device Dissipation<br>Alumina Substrate, <sup>(2)</sup> $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$           | 300         | mW                        |
|   |                 | 2.4         | mW/ $^\circ\text{C}$      |
| Thermal Resistance, Junction to Ambient   | $R_{\theta JA}$ | 417         | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature  | $T_J, T_{stg}$  | -55 to +150 | $^\circ\text{C}$          |

### DEVICE MARKING

BCW33LT1 = D3

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

### OFF CHARACTERISTICS

|   |               |     |     |                 |
|---|---------------|-----|-----|-----------------|
| Collector–Emitter Breakdown Voltage<br>( $I_C = 2.0 \text{ mAdc}, I_B = 0$ )  | $V_{(BR)CEO}$ | 32  | —   | Vdc             |
| Collector–Base Breakdown Voltage<br>( $I_C = 10 \mu\text{Adc}, I_B = 0$ )   | $V_{(BR)CBO}$ | 32  | —   | Vdc             |
| Emitter–Base Breakdown Voltage<br>( $I_E = 10 \mu\text{Adc}, I_C = 0$ )   | $V_{(BR)EBO}$ | 5.0 | —   | Vdc             |
| Collector Cutoff Current<br>( $V_{CB} = 32 \text{ Vdc}, I_E = 0$ )<br>( $V_{CB} = 32 \text{ Vdc}, I_E = 0, T_A = 100^\circ\text{C}$ ) | $I_{CBO}$     | —   | 100 | nAdc            |
|   |               | —   | 10  | $\mu\text{Adc}$ |

- FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.

Thermal Clad is a trademark of the Bergquist Company

# BCW33LT1

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

| Characteristic  | Symbol               | Min  | Max  | Unit            |
|---|----------------------|------|------|-----------------|
| <b>ON CHARACTERISTICS</b>   |                      |      |      |                 |
| DC Current Gain<br>(I <sub>C</sub> = 2.0 mA <sub>dc</sub> , V <sub>CE</sub> = 5.0 V <sub>dc</sub> )   | hFE                  | 420  | 800  | —               |
| Collector–Emitter Saturation Voltage<br>(I <sub>C</sub> = 10 mA <sub>dc</sub> , I <sub>B</sub> = 0.5 mA <sub>dc</sub> )                             | V <sub>CE(sat)</sub> | —    | 0.25 | V <sub>dc</sub> |
| Base–Emitter On Voltage<br>(I <sub>C</sub> = 2.0 mA <sub>dc</sub> , V <sub>CE</sub> = 5.0 V <sub>dc</sub> )   | V <sub>BE(on)</sub>  | 0.55 | 0.70 | V <sub>dc</sub> |
| <b>SMALL–SIGNAL CHARACTERISTICS</b>   |                      |      |      |                 |
| Output Capacitance<br>(V <sub>CB</sub> = 10 V <sub>dc</sub> , I <sub>E</sub> = 0, f = 1.0 MHz)  | C <sub>obo</sub>     | —    | 4.0  | pF              |
| Noise Figure<br>(V <sub>CE</sub> = 5.0 V <sub>dc</sub> , I <sub>C</sub> = 0.2 mA <sub>dc</sub> , R <sub>S</sub> = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz) | NF                   | —    | 10   | dB              |

### EQUIVALENT SWITCHING TIME TEST CIRCUITS

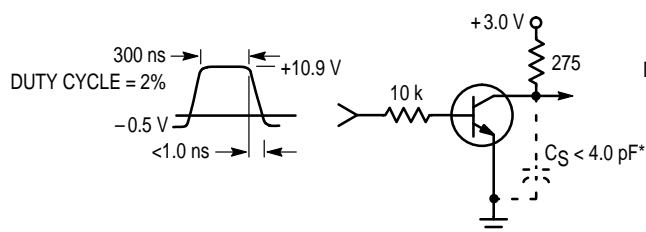


Figure 1. Turn–On Time

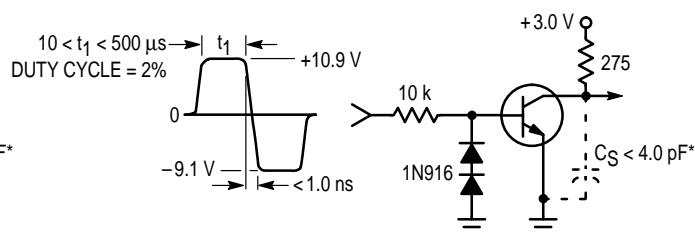


Figure 2. Turn–Off Time

\*Total shunt capacitance of test jig and connectors

TYPICAL NOISE CHARACTERISTICS

( $V_{CE} = 5.0 \text{ Vdc}$ ,  $T_A = 25^\circ\text{C}$ )

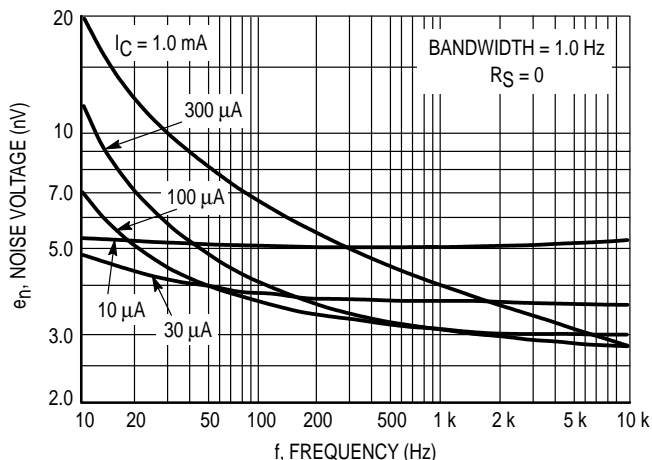


Figure 3. Noise Voltage

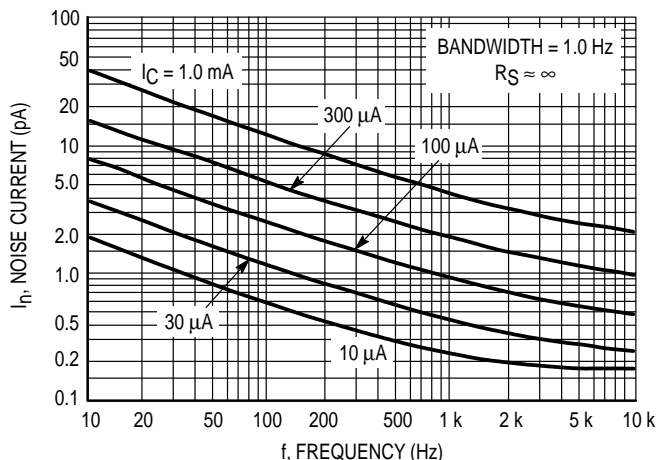


Figure 4. Noise Current

NOISE FIGURE CONTOURS

( $V_{CE} = 5.0 \text{ Vdc}$ ,  $T_A = 25^\circ\text{C}$ )

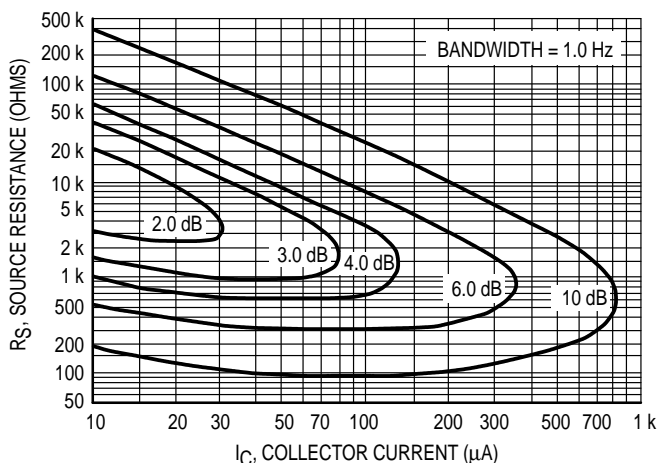


Figure 5. Narrow Band, 100 Hz

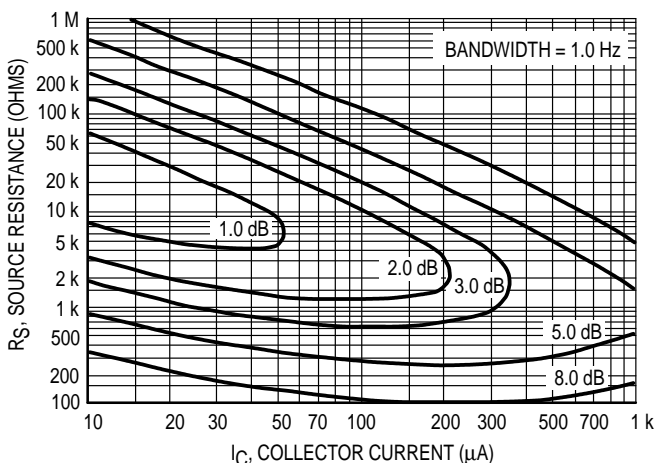


Figure 6. Narrow Band, 1.0 kHz

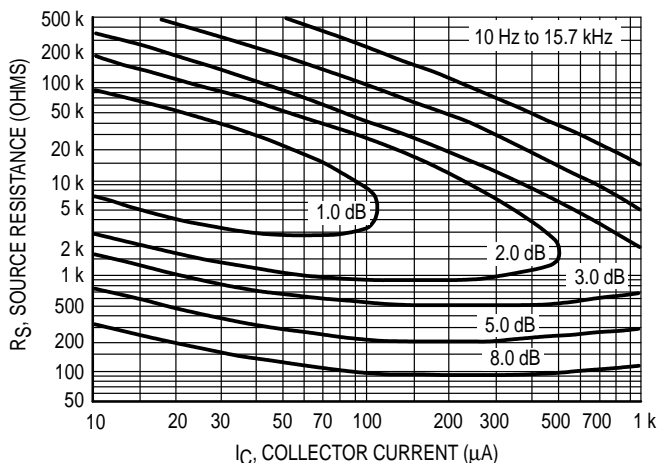


Figure 7. Wideband

Noise Figure is defined as:

$$NF = 20 \log_{10} \left( \frac{e_n^2 + 4KTR_S + I_n^2 R_S^2}{4KTR_S} \right)^{1/2}$$

- $e_n$  = Noise Voltage of the Transistor referred to the input. (Figure 3)
- $I_n$  = Noise Current of the Transistor referred to the input. (Figure 4)
- $K$  = Boltzman's Constant ( $1.38 \times 10^{-23} \text{ J}^\circ\text{K}$ )
- $T$  = Temperature of the Source Resistance ( $^\circ\text{K}$ )
- $R_S$  = Source Resistance (Ohms)

TYPICAL STATIC CHARACTERISTICS

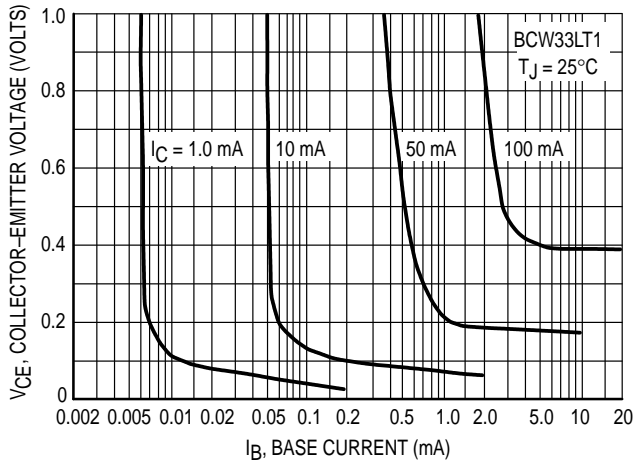


Figure 8. Collector Saturation Region

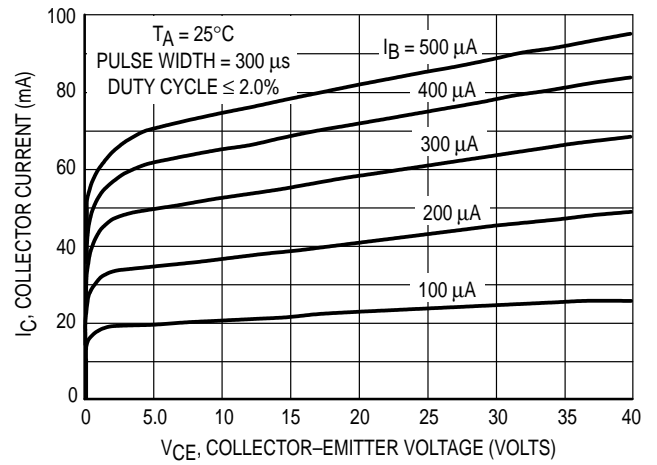


Figure 9. Collector Characteristics

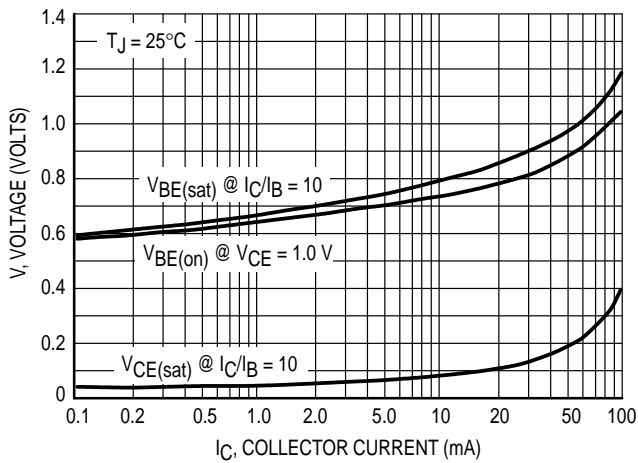


Figure 10. "On" Voltages

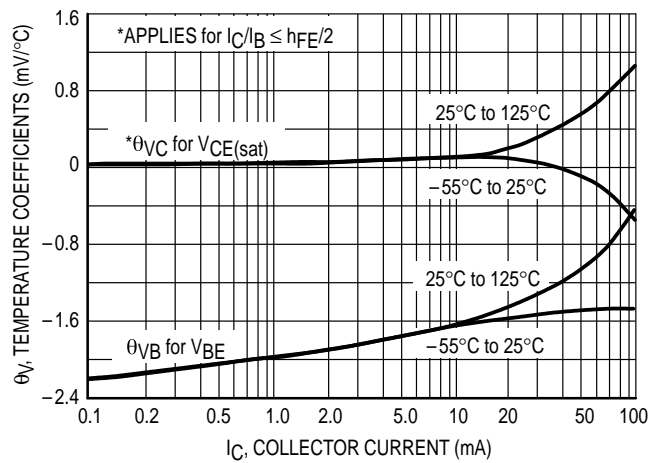


Figure 11. Temperature Coefficients

TYPICAL DYNAMIC CHARACTERISTICS

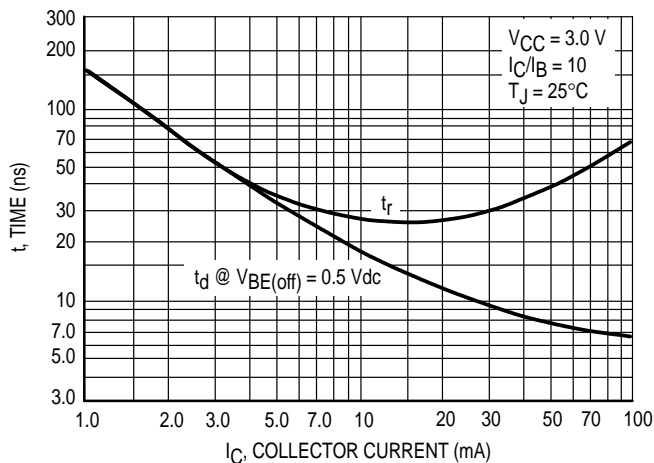


Figure 12. Turn-On Time

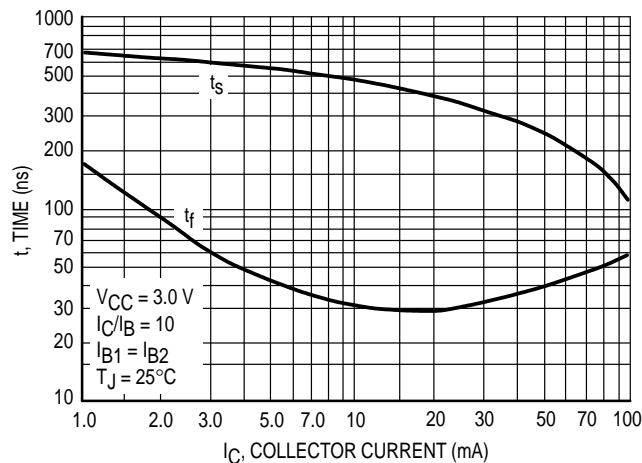


Figure 13. Turn-Off Time

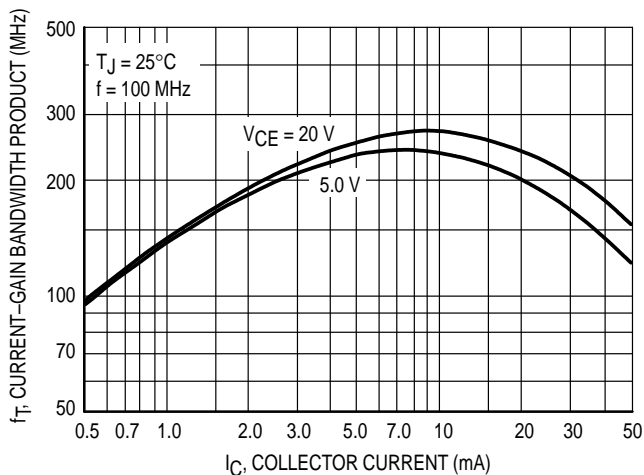


Figure 14. Current-Gain — Bandwidth Product

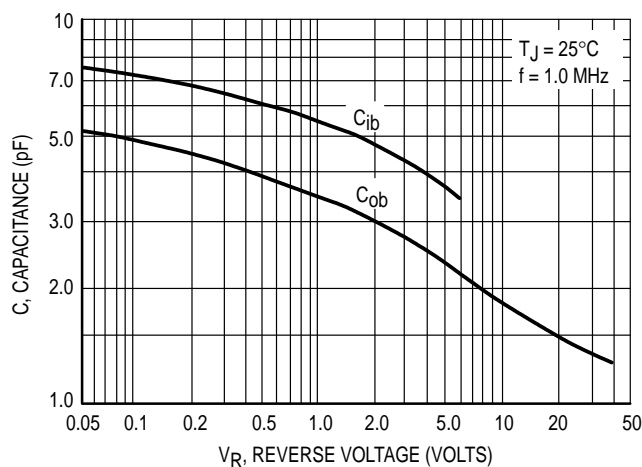


Figure 15. Capacitance

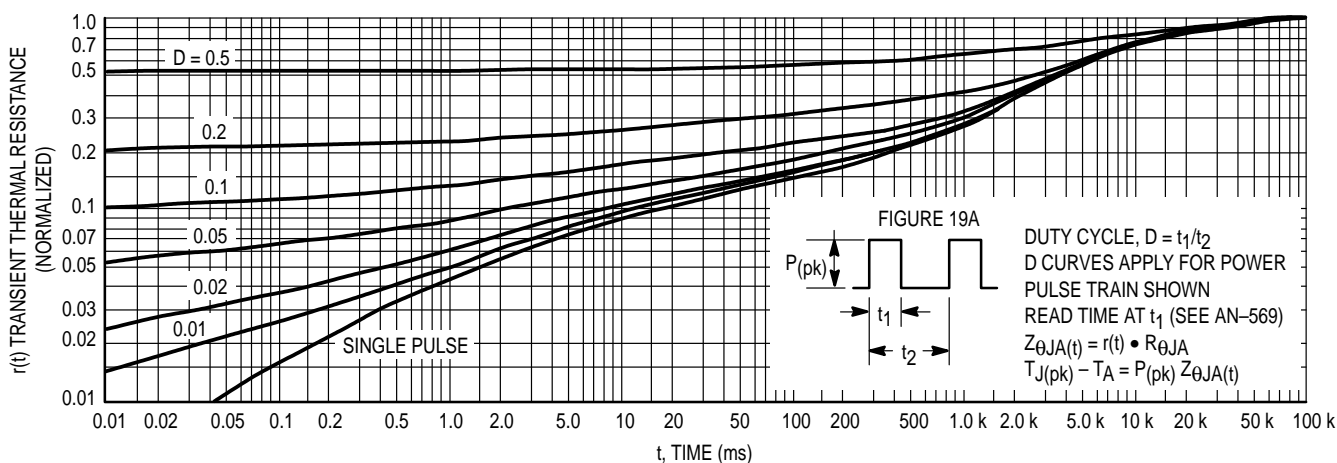


Figure 16. Thermal Response

# BCW33LT1

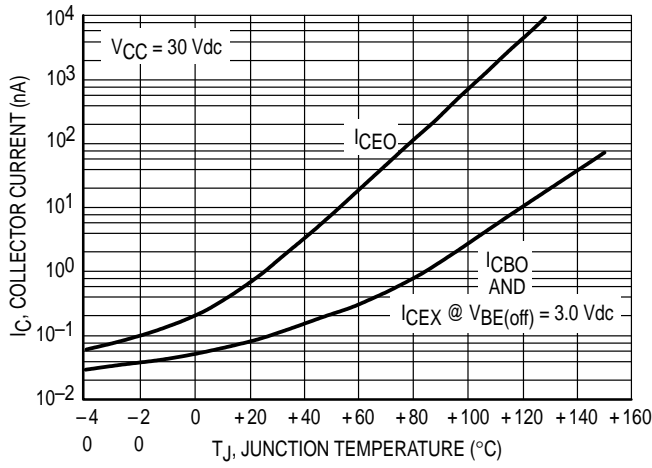


Figure 16A.

## DESIGN NOTE: USE OF THERMAL RESPONSE DATA

A train of periodical power pulses can be represented by the model as shown in Figure 16A. Using the model and the device thermal response the normalized effective transient thermal resistance of Figure 16 was calculated for various duty cycles.

To find  $Z_{\theta JA}(t)$ , multiply the value obtained from Figure 16 by the steady state value  $R_{\theta JA}$ .

Example:

The MPS3904 is dissipating 2.0 watts peak under the following conditions:

$$t_1 = 1.0 \text{ ms}, t_2 = 5.0 \text{ ms. (D = 0.2)}$$

Using Figure 16 at a pulse width of 1.0 ms and D = 0.2, the reading of  $r(t)$  is 0.22.

The peak rise in junction temperature is therefore

$$\Delta T = r(t) \times P_{(pk)} \times R_{\theta JA} = 0.22 \times 2.0 \times 200 = 88^\circ\text{C}.$$

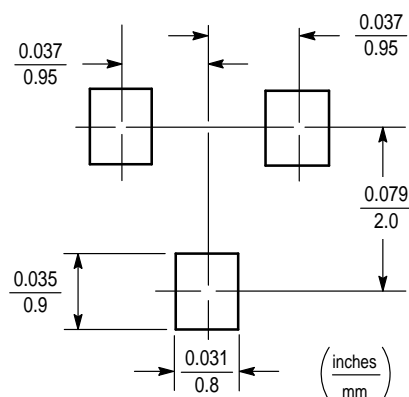
For more information, see AN-569.

## INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



**SOT-23**

### SOT-23 POWER DISSIPATION

The power dissipation of the SOT-23 is a function of the pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(\max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the SOT-23 package,  $P_D$  can be calculated as follows:

$$P_D = \frac{T_{J(\max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{556^\circ\text{C/W}} = 225 \text{ milliwatts}$$

The 556°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

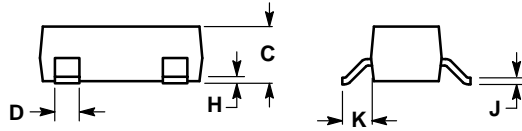
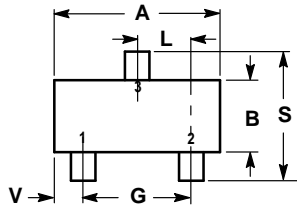
### SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

\* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

PACKAGE DIMENSIONS



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

| DIM | INCHES |        | MILLIMETERS |       |
|-----|--------|--------|-------------|-------|
|     | MIN    | MAX    | MIN         | MAX   |
| A   | 0.1102 | 0.1197 | 2.80        | 3.04  |
| B   | 0.0472 | 0.0551 | 1.20        | 1.40  |
| C   | 0.0350 | 0.0440 | 0.89        | 1.11  |
| D   | 0.0150 | 0.0200 | 0.37        | 0.50  |
| G   | 0.0701 | 0.0807 | 1.78        | 2.04  |
| H   | 0.0005 | 0.0040 | 0.013       | 0.100 |
| J   | 0.0034 | 0.0070 | 0.085       | 0.177 |
| K   | 0.0180 | 0.0236 | 0.45        | 0.60  |
| L   | 0.0350 | 0.0401 | 0.89        | 1.02  |
| S   | 0.0830 | 0.0984 | 2.10        | 2.50  |
| V   | 0.0177 | 0.0236 | 0.45        | 0.60  |

- STYLE 6:
- PIN 1. BASE
  - EMITTER
  - COLLECTOR

CASE 318-08  
ISSUE AE  
SOT-23 (TO-236AB)

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